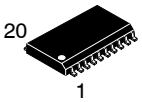
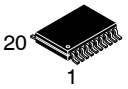
# Low-Voltage CMOS Octal D-Type Flip-Flop

## With 5 V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

# MC74LCX374




**SOIC−20 WB**
**DW SUFFIX**
**CASE 751D**




**TSSOP−20**
**DT SUFFIX**
**CASE 948E**

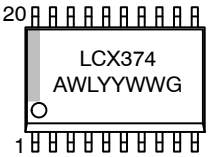
The MC74LCX374 is a high performance, non−inverting octal D−type flip−flop operating from a 2.3 to 3.6 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A $V_I$ specification of 5.5 V allows MC74LCX374 inputs to be safely driven from 5 V devices.

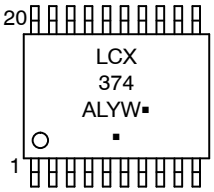
The MC74LCX374 consists of 8 edge−triggered flip−flops with individual D−type inputs and 3−state true outputs. The buffered clock and buffered Output Enable ($\overline{OE}$) are common to all flip−flops. The eight flip−flops will store the state of individual D inputs that meet the setup and hold time requirements on the LOW−to−HIGH Clock (CP) transition. With the $\overline{OE}$ LOW, the contents of the eight flip−flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. The $\overline{OE}$ input level does not affect the operation of the flip−flops.

### Features

- Designed for 2.3 to 3.6 V $V_{CC}$ Operation
- 5 V Tolerant − Interface Capability With 5 V TTL Logic
- Supports Live Insertion and Withdrawal
- $I_{OFF}$ Specification Guarantees High Impedance When $V_{CC}$ = 0 V
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10 μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- ESD Performance:
  - ♦ Human Body Model >2000 V
  - ♦ Machine Model >200 V
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

### MARKING DIAGRAMS




| | | |
|---|---|---|
| A | = | Assembly Location |
| L, WL | = | Wafer Lot |
| Y, YY | = | Year |
| W, WW | = | Work Week |
| G or ▪ | = | Pb−Free Package |

(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 6.

© Semiconductor Components Industries, LLC, 2014

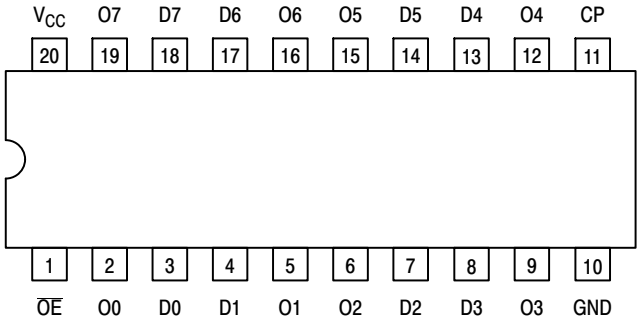



**Figure 1. Pinout: 20−Lead** (Top View)

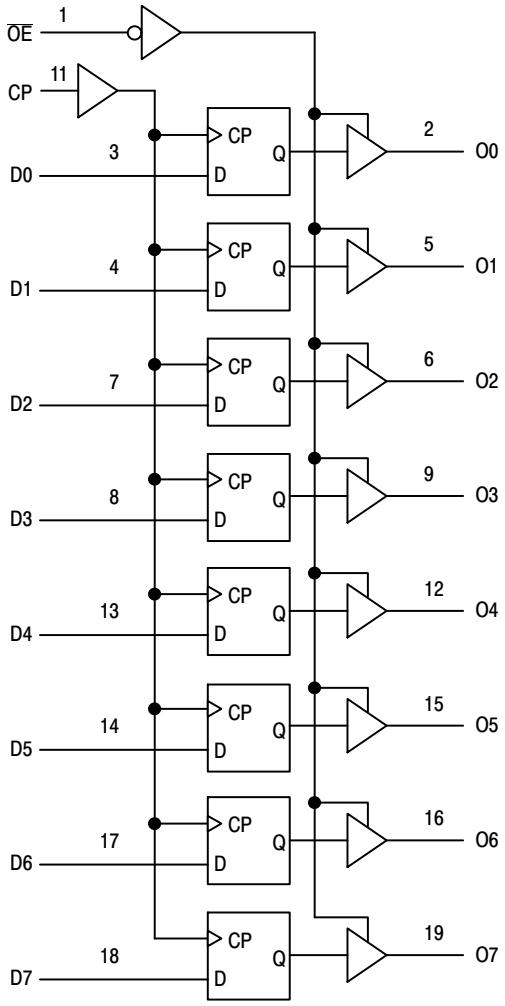



**Figure 2. LOGIC DIAGRAM**

**PIN NAMES**

| Pins | Function |
|---|---|
| $\overline{OE}$ | Output Enable Input |
| CP | Clock Pulse Input |
| D0−D7 | Data Inputs |
| O0−O7 | 3−State Outputs |

**TRUTH TABLE**

| INPUTS | | | OUTPUTS | OPERATING MODE |
|---|---|---|---|---|
| $\overline{OE}$ | CP | Dn | On | |
| L<br>L | ↑<br>↑ | l<br>h | L<br>H | Load and Read Register |
| L | ↑̸ | X | NC | Hold and Read Register |
| H | ↑̸ | X | Z | Hold and Disable Outputs |
| H<br>H | ↑<br>↑ | l<br>h | Z<br>Z | Load Internal Register and Disable Outputs |

H = High Voltage Level
h = High Voltage Level One Setup Time Prior to the Low−to−High Clock Transition
L = Low Voltage Level
l = Low Voltage Level One Setup Time Prior to the Low−to−High Clock Transition
NC = No Change, State Prior to Low−to−High Clock Transition
X = High or Low Voltage Level and Transitions are Acceptable
Z = High Impedance State
↑ = Low−to−High Transition
↑̸ = Not a Low−to−High Transition; For $I_{CC}$ Reasons, DO NOT FLOAT Inputs

## MAXIMUM RATINGS

| Symbol | Parameter | Value | Condition | Units |
|---|---|---|---|---|
| $V_{CC}$ | DC Supply Voltage | −0.5 to +7.0 | | V |
| $V_I$ | DC Input Voltage | $-0.5 \le V_I \le +7.0$ | | V |
| $V_O$ | DC Output Voltage | $-0.5 \le V_O \le +7.0$ | Output in 3−State | V |
| | | $-0.5 \le V_O \le V_{CC} + 0.5$ | (Note 1) | V |
| $I_{IK}$ | DC Input Diode Current | −50 | $V_I < GND$ | mA |
| $I_{OK}$ | DC Output Diode Current | −50 | $V_O < GND$ | mA |
| | | +50 | $V_O > V_{CC}$ | mA |
| $I_O$ | DC Output Source/Sink Current | ±50 | | mA |
| $I_{CC}$ | DC Supply Current Per Supply Pin | ±100 | | mA |
| $I_{GND}$ | DC Ground Current Per Ground Pin | ±100 | | mA |
| $T_{STG}$ | Storage Temperature Range | −65 to +150 | | °C |
| MSL | Moisture Sensitivity | | Level 1 | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Output in HIGH or LOW State. $I_O$ absolute maximum rating must be observed.

## RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Typ | Max | Units |
|---|---|---|---|---|---|
| $V_{CC}$ | Supply Voltage<br>Operating<br>Data Retention Only | <br>2.0<br>1.5 | <br>3.3<br>3.3 | <br>3.6<br>3.6 | V |
| $V_I$ | Input Voltage | 0 | | 5.5 | V |
| $V_O$ | Output Voltage<br>(HIGH or LOW State)<br>(3−State) | <br>0<br>0 | | <br>$V_{CC}$<br>5.5 | V |
| $I_{OH}$ | HIGH Level Output Current, $V_{CC}$ = 3.0 V − 3.6 V | | | −24 | mA |
| $I_{OL}$ | LOW Level Output Current, $V_{CC}$ = 3.0 V − 3.6 V | | | 24 | mA |
| $I_{OH}$ | HIGH Level Output Current, $V_{CC}$ = 2.7 V − 3.0 V | | | −12 | mA |
| $I_{OL}$ | LOW Level Output Current, $V_{CC}$ = 2.7 V − 3.0 V | | | 12 | mA |
| $T_A$ | Operating Free−Air Temperature | −40 | | +85 | °C |
| $\Delta t/\Delta V$ | Input Transition Rise or Fall Rate, $V_{IN}$ from 0.8 V to 2.0 V, $V_{CC}$ = 3.0 V | 0 | | 10 | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## DC ELECTRICAL CHARACTERISTICS

| Symbol | Characteristic | Condition | $T_A$ = −40°C to +85°C | | Units |
|---|---|---|---|---|---|
| | | | Min | Max | |
| $V_{IH}$ | HIGH Level Input Voltage (Note 2) | 2.7 V ≤ $V_{CC}$ ≤ 3.6 V | 2.0 | | V |
| $V_{IL}$ | LOW Level Input Voltage (Note 2) | 2.7 V ≤ $V_{CC}$ ≤ 3.6 V | | 0.8 | V |
| $V_{OH}$ | HIGH Level Output Voltage | 2.7 V ≤ $V_{CC}$ ≤ 3.6 V; $I_{OH}$ = −100 μA | $V_{CC}$ − 0.2 | | V |
| | | $V_{CC}$ = 2.7 V; $I_{OH}$ = −12 mA | 2.2 | | |
| | | $V_{CC}$ = 3.0 V; $I_{OH}$ = −18 mA | 2.4 | | |
| | | $V_{CC}$ = 3.0 V; $I_{OH}$ = −24 mA | 2.2 | | |
| $V_{OL}$ | LOW Level Output Voltage | 2.7 V ≤ $V_{CC}$ ≤ 3.6 V; $I_{OL}$ = 100 μA | | 0.2 | V |
| | | $V_{CC}$ = 2.7 V; $I_{OL}$ = 12 mA | | 0.4 | |
| | | $V_{CC}$ = 3.0 V; $I_{OL}$ = 16 mA | | 0.4 | |
| | | $V_{CC}$ = 3.0 V; $I_{OL}$ = 24 mA | | 0.55 | |
| $I_{OZ}$ | 3−State Output Current | $V_{CC}$ = 3.6 V, $V_{IN}$ = $V_{IH}$ or $V_{IL}$, $V_{OUT}$ = 0 to 5.5 V | | ±5 | μA |
| $I_{OFF}$ | Power Off Leakage Current | $V_{CC}$ = 0, $V_{IN}$ = 5.5 V or $V_{OUT}$ = 5.5 V | | 10 | μA |
| $I_{IN}$ | Input Leakage Current | $V_{CC}$ = 3.6 V, $V_{IN}$ = 5.5 V or GND | | ±5 | μA |
| $I_{CC}$ | Quiescent Supply Current | $V_{CC}$ = 3.6 V, $V_{IN}$ = 5.5 V or GND | | 10 | μA |
| $\Delta I_{CC}$ | Increase in $I_{CC}$ per Input | 2.3 ≤ $V_{CC}$ ≤ 3.6 V; $V_{IH}$ = $V_{CC}$ − 0.6 V | | 500 | μA |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. These values of $V_I$ are used to test DC electrical characteristics only.

## AC CHARACTERISTICS ($t_R$ = $t_F$ = 2.5 ns; $C_L$ = 50 pF; $R_L$ = 500 Ω)

| Symbol | Parameter | Waveform | Limits | | | | Units |
|---|---|---|---|---|---|---|---|
| | | | $T_A$ = −40°C to +85°C | | | | |
| | | | $V_{CC}$ = 3.0 V to 3.6 V | | $V_{CC}$ = 2.7 V | | |
| | | | Min | Max | Min | Max | |
| $f_{max}$ | Clock Pulse Frequency | 1 | 150 | | | | MHz |
| $t_{PLH}$<br>$t_{PHL}$ | Propagation Delay<br>CP to $O_n$ | 1 | 1.5<br>1.5 | 8.5<br>8.5 | 1.5<br>1.5 | 9.5<br>9.5 | ns |
| $t_{PZH}$<br>$t_{PZL}$ | Output Enable Time to HIGH and LOW Levels | 2 | 1.5<br>1.5 | 8.5<br>8.5 | 1.5<br>1.5 | 9.5<br>9.5 | ns |
| $t_{PHZ}$<br>$t_{PLZ}$ | Output Disable Time from HIGH and LOW Levels | 2 | 1.5<br>1.5 | 7.5<br>7.5 | 1.5<br>1.5 | 8.5<br>8.5 | ns |
| $t_s$ | Setup TIme, HIGH or LOW $D_n$ to CP | 1 | 2.5 | | 2.5 | | ns |
| $t_h$ | Hold TIme, HIGH or LOW $D_n$ to CP | 1 | 1.5 | | 1.5 | | ns |
| $t_w$ | CP Pulse Width, HIGH or LOW | 3 | 3.3 | | 3.3 | | ns |
| $t_{OSHL}$<br>$t_{OSLH}$ | Output−to−Output Skew (Note 3) | | | 1.0<br>1.0 | | | ns |

3. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH−to−LOW ($t_{OSHL}$) or LOW−to−HIGH ($t_{OSLH}$); parameter guaranteed by design.

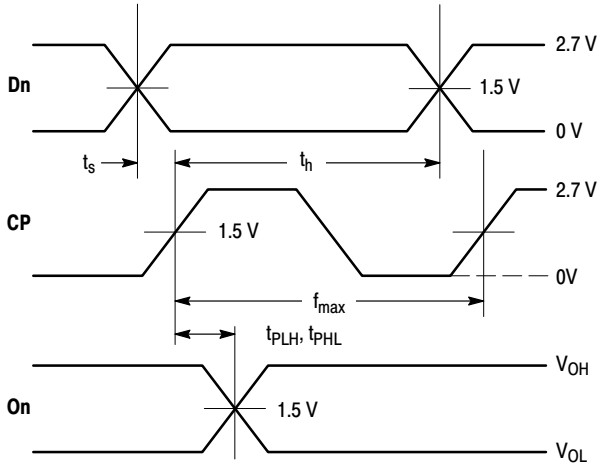
## DYNAMIC SWITCHING CHARACTERISTICS

| Symbol | Characteristic | Condition | $T_A$ = +25°C | | | Units |
|---|---|---|---|---|---|---|
| | | | Min | Typ | Max | |
| $V_{OLP}$ | Dynamic LOW Peak Voltage (Note 4) | $V_{CC}$ = 3.3 V, $C_L$ = 50 pF, $V_{IH}$ = 3.3 V, $V_{IL}$ = 0 V | | 0.8 | | V |
| $V_{OLV}$ | Dynamic LOW Valley Voltage (Note 4) | $V_{CC}$ = 3.3 V, $C_L$ = 50 pF, $V_{IH}$ = 3.3 V, $V_{IL}$ = 0 V | | 0.8 | | V |

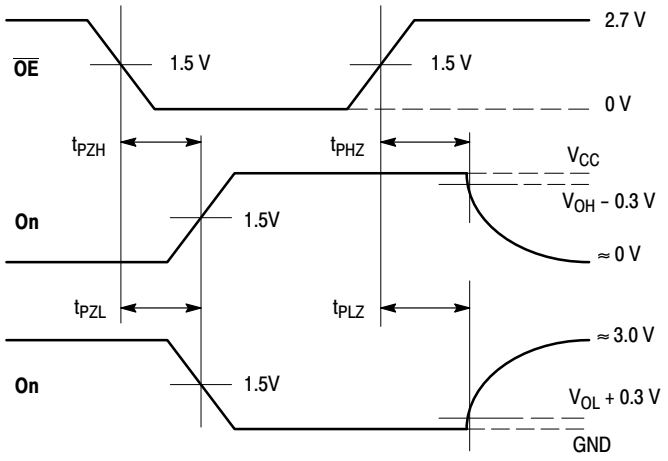
4. Number of outputs defined as “n”. Measured with “n−1” outputs switching from HIGH−to−LOW or LOW−to−HIGH. The remaining output is measured in the LOW state.

## CAPACITIVE CHARACTERISTICS

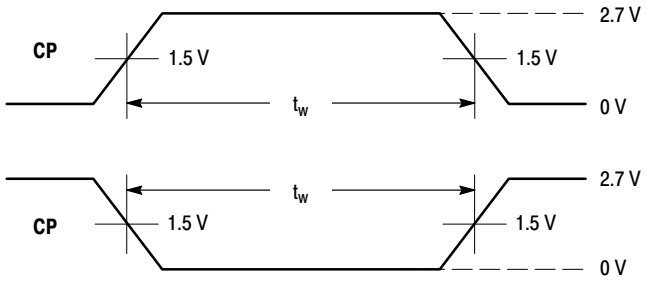
| Symbol | Parameter | Condition | Typical | Units |
|---|---|---|---|---|
| $C_{IN}$ | Input Capacitance | $V_{CC}$ = 3.3 V, $V_I$ = 0 V or $V_{CC}$ | 7 | pF |
| $C_{OUT}$ | Output Capacitance | $V_{CC}$ = 3.3 V, $V_I$ = 0 V or $V_{CC}$ | 8 | pF |
| $C_{PD}$ | Power Dissipation Capacitance | 10 MHz, $V_{CC}$ = 3.3 V, $V_I$ = 0 V or $V_{CC}$ | 25 | pF |




**WAVEFORM 1 – PROPAGATION DELAYS, SETUP AND HOLD TIMES**
$t_R = t_F$ = 2.5 ns, 10% to 90%; f = 1 MHz; $t_W$ = 500 ns

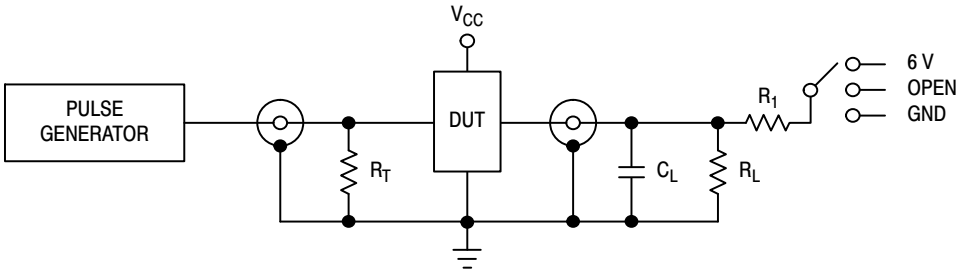



**WAVEFORM 2 – OUTPUT ENABLE AND DISABLE TIMES**
$t_R = t_F$ = 2.5 ns, 10% to 90%; f = 1 MHz; $t_W$ = 500 ns




**WAVEFORM 3 – PULSE WIDTH**
$t_R = t_F$ = 2.5 ns (or fast as required) from 10% to 90%;
Output requirements: $V_{OL} \le 0.8$ V, $V_{OH} \ge 2.0$ V

**Figure 3. AC Waveforms**




| TEST | SWITCH |
|---|---|
| $t_{PLH}$, $t_{PHL}$ | Open |
| $t_{PZL}$, $t_{PLZ}$ | 6 V |
| Open Collector/Drain $t_{PLH}$ and $t_{PHL}$ | 6 V |
| $t_{PZH}$, $t_{PHZ}$ | GND |

$C_L$ = 50 pF or equivalent (Includes jig and probe capacitance)
$R_L$ = $R_1$ = 500 Ω or equivalent
$R_T$ = $Z_{OUT}$ of pulse generator (typically 50 Ω)

**Figure 4. Test Circuit**

## ORDERING INFORMATION

| Device | Package | Shipping† |
|---|---|---|
| MC74LCX374DWR2G | SOIC−20 WB (Pb−Free) | 1000 / Tape & Reel |
| MC74LCX374DTR2G | TSSOP−20 (Pb−Free) | 2500 / Tape & Reel |

**DISCONTINUED** (Note 5)

| | | |
|---|---|---|
| NLV74LCX374DTR2G* | TSSOP−20 (Pb−Free) | 2500 / Tape & Reel |

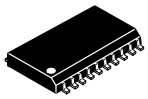
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

5. **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on www.onsemi.com.

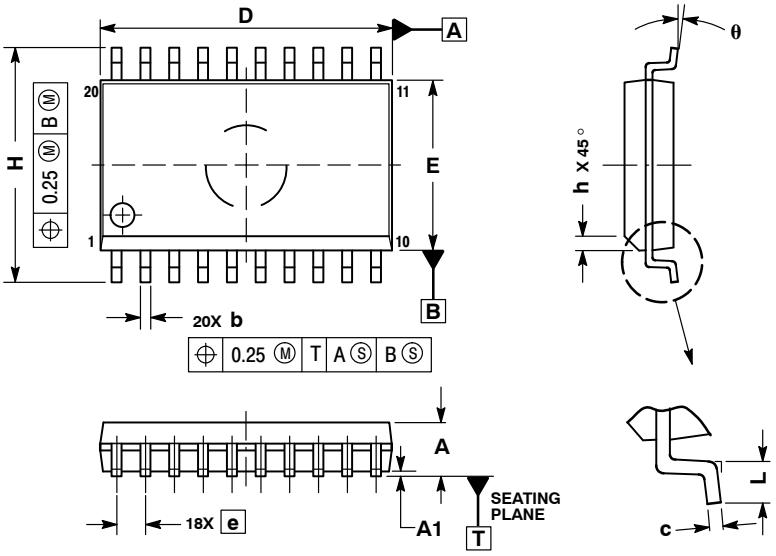
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable.

**SOIC−20 WB**
CASE 751D−05
ISSUE H

DATE 22 APR 2015



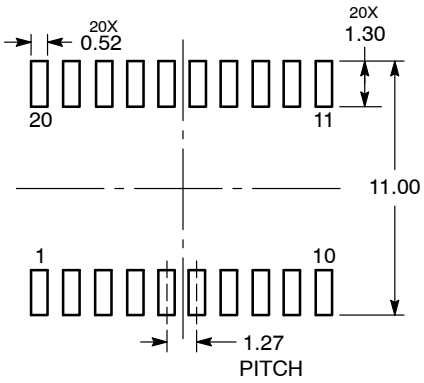
**SCALE 1:1**




NOTES:
1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

| | MILLIMETERS | |
|---|---|---|
| DIM | MIN | MAX |
| A | 2.35 | 2.65 |
| A1 | 0.10 | 0.25 |
| b | 0.35 | 0.49 |
| c | 0.23 | 0.32 |
| D | 12.65 | 12.95 |
| E | 7.40 | 7.60 |
| e | 1.27 BSC | |
| H | 10.05 | 10.55 |
| h | 0.25 | 0.75 |
| L | 0.50 | 0.90 |
| θ | 0° | 7° |

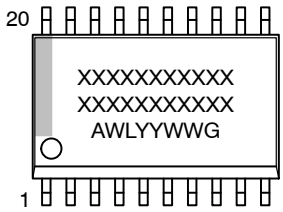
## RECOMMENDED SOLDERING FOOTPRINT*




DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## GENERIC MARKING DIAGRAM*




XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

| | | |
|---|---|---|
| **DOCUMENT NUMBER:** | **98ASB42343B** | Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| **DESCRIPTION:** | **SOIC−20 WB** | **PAGE 1 OF 1** |

**onsemi** and onsemi are trademarks of Semiconductor Components Industries, LLC dba **onsemi** or its subsidiaries in the United States and/or other countries. **onsemi** reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. **onsemi** does not convey any license under its patent rights nor the rights of others.

**onsemi**, ONSEMI , and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent−Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as−is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## ADDITIONAL INFORMATION

**TECHNICAL PUBLICATIONS**:
**Technical Library:** www.onsemi.com/design/resources/technical−documentation
**onsemi Website:** www.onsemi.com

**ONLINE SUPPORT**: www.onsemi.com/support
**For additional information, please contact your local Sales Representative at** www.onsemi.com/support/sales